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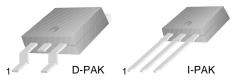
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### **KSH112**

### **D-PAK for Surface Mount Applications**

- High DC Current Gain
- Built-in a Damper Diode at E-C
- Lead Formed for Surface Mount Applications (No Suffix)
- Straight Lead (I-PAK, " I " Suffix)
- Electrically Similar to Popular TIP112

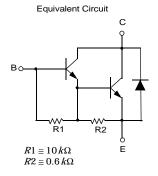


1.Base 2.Collector 3.Emitter

# **NPN Silicon Darlington Transistor**

### Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

| Symbol           | Parameter                                    | Value      | Units |
|------------------|--|------------|-------|
| V <sub>CBO</sub> | Collector-Base Voltage                       | 100        | V     |
| V <sub>CEO</sub> | Collector-Emitter Voltage                    | 100        | V     |
| V <sub>EBO</sub> | Emitter-Base Voltage                         | 5          | V     |
| I <sub>C</sub>   | Collector Current (DC)                       | 2          | Α     |
| I <sub>CP</sub>  | Collector Current (Pulse)                    | 4          | Α     |
| I <sub>B</sub>   | Base Current                                 | 50         | mA    |
| P <sub>C</sub>   | Collector Dissipation (T <sub>C</sub> =25°C) | 20         | W     |
|                  | Collector Dissipation (T <sub>a</sub> =25°C) | 1.75       | W     |
| T <sub>J</sub>   | Junction Temperature                         | 150        | °C    |
| T <sub>STG</sub> | Storage Temperature                          | - 65 ~ 150 | °C    |



### Electrical Characteristics $\rm T_C = 25\,^{\circ}C$ unless otherwise noted

| Symbol                 | Parameter                              | Test Condition                | Min. | Max. | Units |
|------------------------|--|-------------------------------|------|------|-------|
| V <sub>CEO</sub> (sus) | Collector-Emitter Sustaining Voltage   | $I_C = 30 \text{mA}, I_B = 0$ | 100  |      | V     |
| I <sub>CEO</sub>       | Collector Cut-off Current              | $V_{CE} = 50V, I_{B} = 0$     |      | 20   | μΑ    |
| I <sub>CBO</sub>       | Collector Cut-off Current              | $V_{CB} = 100V, I_{B} = 0$    |      | 20   | μΑ    |
| I <sub>EBO</sub>       | Emitter Cut-off Current                | $V_{EB} = 5V, I_{C} = 0$      |      | 2    | mA    |
| h <sub>FE</sub>        | * DC Current Gain                      | $V_{CE} = 3V, I_{C} = 0.5A$   | 500  |      |       |
|                        |  | $V_{CE} = 3V, I_{C} = 2A$     | 1000 | 12K  |       |
|                        |  | $V_{CE} = 3V, I_{C} = 4A$     | 200  |      |       |
| V <sub>CE</sub> (sat)  | * Collector-Emitter Saturation Voltage | $I_C = 2A, I_B = 8mA$         |      | 2    | V     |
|                        |  | $I_C = 4A, I_B = 40mA$        |      | 3    | V     |
| V <sub>BE</sub> (sat)  | * Base-Emitter Saturation Voltage      | $I_C = 4A, I_B = 40mA$        |      | 4    | V     |
| V <sub>BE</sub> (on)   | * Base-Emitter On Voltage              | $V_{CE} = 3A, I_{C} = 2A$     |      | 2.8  | V     |
| f <sub>T</sub>         | Current Gain Bandwidth Product         | $V_{CE} = 10V, I_{C} = 0.75A$ | 25   |      | MHz   |
| C <sub>ob</sub>        | Output Capacitance                     | $V_{CB} = 10V, I_{E} = 0$     |      | 100  | pF    |
|                        |  | f = 0.1MHz                    |      |      |       |

<sup>\*</sup> Pulse Test: PW≤300µs, Duty Cycle≤2%

# **Typical Characteristics**

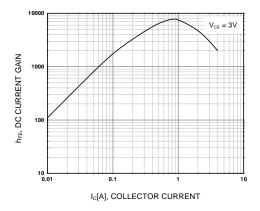


Figure 1. DC current Gain

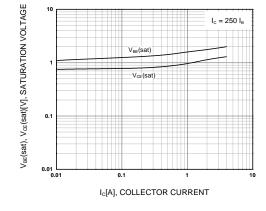


Figure 2. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

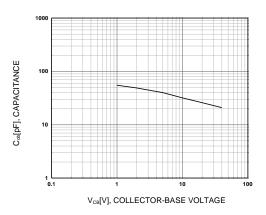


Figure 3. Collector Output Capacitance

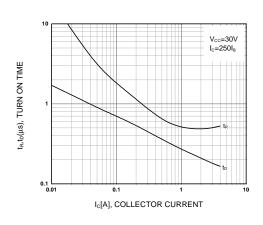


Figure 4. Turn On Time

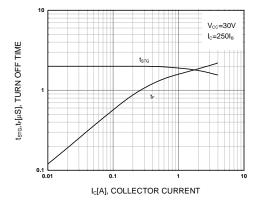


Figure 5. Turn Off Time

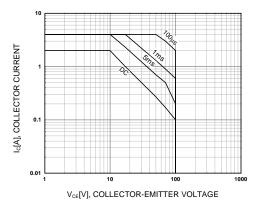


Figure 6. Safe Operating Area

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# Typical Characteristics (Continued)

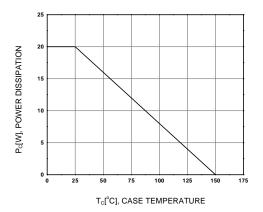
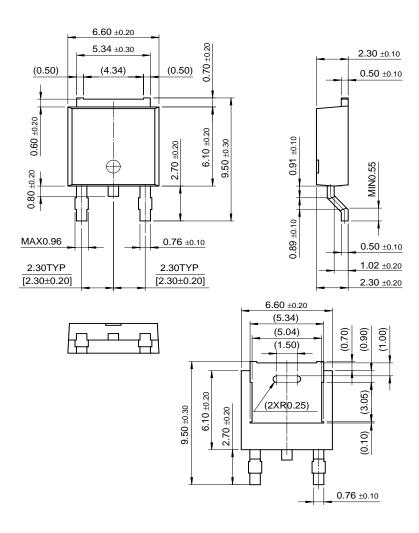


Figure 7. Power Derating

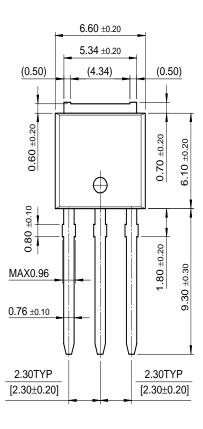
# **Package Dimensions**

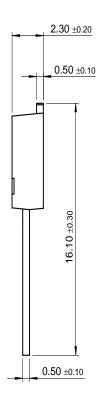
# D-PAK



# Package Dimensions (Continued)

# I-PAK







Dimensions in Millimeters

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| CoolFET™                             | FASTr™              | MicroFET™              | PowerTrench <sup>®</sup> | SuperSOT™-6           |
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